





KMY20



KMZ20

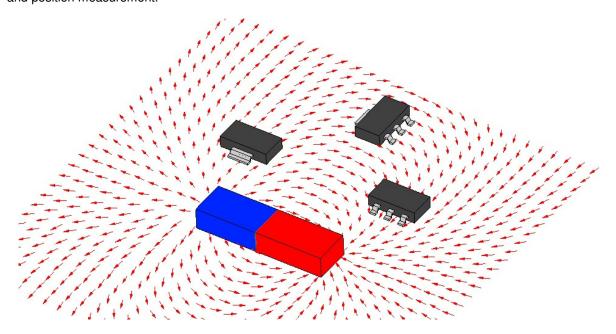
AMR sensor

- Very high sensitivity
- Almost no hysteresis
- Various applications
- Available with internal magnet
- Available in several packages

KMY22

DESCRIPTION

Due to its featured properties - high sensitivity and almost no hysteresis – the KMY / KMZ sensors are used in a wide range of applications, like magnetic field measurement, revolution counters, proximity detecting, and position measurement.



An uniaxial linear magnetic field will generate a linear output within the specified magnetic field range.

FEATURES

APPLICATIONS

- Output proportional to magnetic field strength with very high sensitivity
- Very small hysteresis
- Large operating temperature range, from -40 °C up to +150 °C
- Highly reliable
- With / without internal magnet

- Detection of very weak magnetic fields, like earth magnetic field, or field generated by small magnetic particles
- Detection of objects that distort non-local magnetic fields
- Revolution measurement on ferromagnetic gears
- Contactless switch
- Contactless displacement / position sensor



DESCRIPTION

An uniaxial linear magnetic field (in y-direction) will generate a linear output within the specified magnetic field range. The sensor is available in two types: the KMY 20 M, KMY 21 M and KMZ 20 M sensor types contain intrinsic magnets which provide an auxiliary magnetic field (in x-direction) at the sensor die which prevents magnetic domains from flipping irregularly.

Auxiliary Field Dependence

If the dies MR174B or the components KMY22, KMY20S or KMZ20S are used, the auxiliary field has to be provided by the user. The dependence of the sensitivity with auxiliary field strength is depicted in the figure aside.

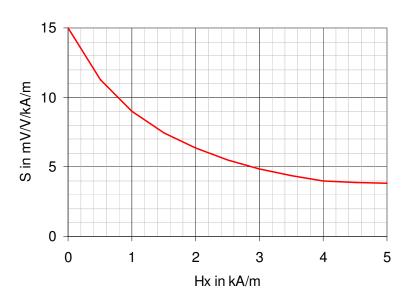


Figure 1: Sensitivity dependence on auxiliary field strength

Auxiliary field strengths below Hx<1.5 kA/m are not recommended, as small disturbances may flip the magnetization domains. Sometimes, the magnetic conditions in the application may provide enough Hx bias field stabilization. MEAS Germany can provide advise for customer specific magnet arrangements.

If a bias field Hx is not applied or Hx is less than 2.5 kA/m, the sensor may be used only in a limited field range Hy, depending on the present total bias field Hx,tot. In this case, it is strongly recommended to 'premagnetize' the sensor, i.e. align all magnetic domains consistently, prior to the measurement.

Hx,tot is the sum of all acting magnetic fields in x direction at the sensor die.

Do not use the sensor outside the safe operating area. Leaving the save operating area can destroy an existing premagnetization and therefore will lead to unreproducible sensor signals.

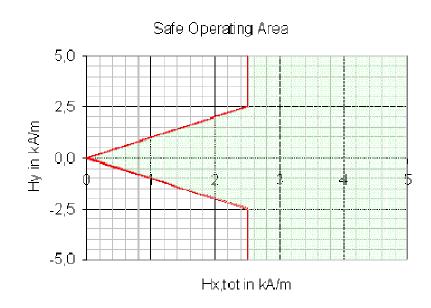


Figure 2: Safe operating area



CHARACTERISTIC VALUES / SENSOR SPECIFICATIONS

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Operating Limits			_			•
max. supply voltage	V _{cc,max}				10	V
max. current	I _{cc,max}	SOT223			9	mA
		E-Line			9	mA
operating temperature	T _{op}	SOT223, E-Line	-40		+150	°C
storage temperature	T _{st}	SOT223, E-Line	-40		+150	°C
General Sensor Specific	ations		•		•	
TC of amplitude	TCSV	Condition A, C	-0.36	-0.32	-0.28	%/K
TC of resistance	TCBR	Condition A, C	+0.27	+0.32	+0.37	%/K
TC of offset	TCVoff	Condition A, C	-4	0	+4	μV/V/K
Sensor Specifications k	MY 20, KMZ	20 (T=25 ℃, Hx=3 kA/m))			•
Supply voltage	V _{cc}	Condition A, B		5		V
Bridge resistance	R _b	Condition A, B	1200	1700	2200	Ω
Output signal range	$\Delta V_0/V_{cc}$	Condition A, B	16	20	24	mV/V
Offset voltage	V _{off} /V _{cc}	Condition A, B	-1	0	+1	mV/V
Sensitivity	S	Condition A, B	3.7	4.7	5.7	mV/V/kA/m
Hysteresis	V _H /V _{cc}	Condition A, B	-	-	50	μV/V
Sensor Specifications k	MY 21 M (T=	25 ℃, Hx=2.5 kA/m)	•		•	
Supply voltage	V _{cc}	Condition A, B		5		V
Bridge resistance	R _b	Condition A, B	1100	1500	1900	Ω
Output signal range	$\Delta V_0/V_{cc}$	Condition A, B	8	9.5	12	mV/V
Offset voltage	V _{off} /V _{cc}	Condition A, B	48	50	52	%Vcc
Sensitivity	S	Condition A, B	2.05	2.50	3.10	mV/V/kA/m
Hysteresis	V _H /V _{cc}	Condition A, B	-	-	50	μV/V

Stress above one or more of the limiting values may cause permanent damage to the device. Exposure to limiting values for extended periods may affect device reliability.



MEASUREMENT CONDITIONS

Parameter	Symbol	Unit	Condition			
Condition A: Set Up Co	onditions					
Ambient temperature	Т	℃	23±5			
Supply voltage	V_{cc}	V	5			
Output voltage	V _O V _O /V _{cc}	mV mV/V	$V_{O}=(V_{0+}-V_{0-})$ output voltages are also given independently on supply voltage: example: $V_{O}/V_{C}=(V_{0+}-V_{0-})/V_{C}$ measure MR half bridge against reference half bridge			
Reference half bridge			2* 2 kΩ 0.1%			
for full to (KMY20S, KMY20M,	oridge sensor KMY22, KMZ		for half bridge sensors (KMY 21 M)			
V0+ X 1	VCC ×3 3 	² X ∪0-	2K 0,1% Reference half bridge			
0.10			The output voltage of the MR half bridge is measured against a reference half bridge			
Condition B: Sensor S	pecifications	(T=23±5 °C, Hx=3	.0±0.5 kA/m)			
Output voltage range	$\Delta V_{O}/V_{cc}$	mV/V	$H_y = -7+7 \ kA/m; \ \Delta V_O = (V_{O,\text{max}} - V_{O,\text{min}})$			
Offset voltage	V _{off} /V _{cc}	mV/V	$H_y = 0; V_{off} = V_O(H_y)$			
Sensitivity	S	(mV/V)/(kA/m)	$H_{y} = 1 kA/m; S := \frac{V_{0}(+H_{y}) - V_{0}(-H_{y})}{2 \cdot V_{cc}}$			
Hysteresis	V _H /V _{cc}	μV/V	Hy in kA/m $(V_0(H_y=0;H_y=-1\rightarrow +1) \\ -V_0(H_y=0;H_y=+1\rightarrow -1))/V_{cc}$			
Condition C: Sensor S	pecifications	(reference temper	ratures T=-25 ℃, +125 ℃)			
Ambient temperatures	Т	℃	T ₁ =-25 °C, T ₀ =+25 °C, T ₂ =+125 °C			
TC of amplitude	TCSV	%/K	$TCV = \frac{1}{(T_2 - T_1)} \cdot \frac{\Delta V_0 / V_{cc}(T_2) - \Delta V_0 / V_{cc}(T_1)}{\Delta V_0 / V_{cc}(T_1)} \cdot 100$			
TC of resistance	TCBR	%/K	$TCR = \frac{1}{(T_2 - T_1)} \cdot \frac{R(T_2) - R(T_1)}{R(T_1)} \cdot 100\%$			
TC of offset	TCVoff	(μV/V)/K	$V_{off}(T) = V_{off}(T)$			

 $\frac{\textit{Voff}(T_2) - \textit{Voff}(T_1)}{(T_2 - T_1)}$

(μV/V)/K

TC of offset



SENSOR MODELS

KMY 20 / KMY 22 / KMZ 20

The KMY and KMZ sensors are highly sensitive magnetic field sensors which utilize the anisotropic magneto resistance effect. The KMY 20 and KMZ 20 sensors contain a Wheatstone bridge.

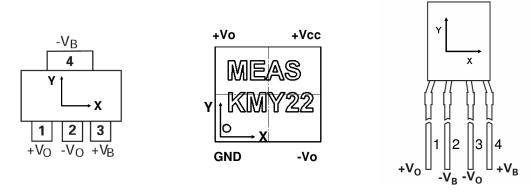
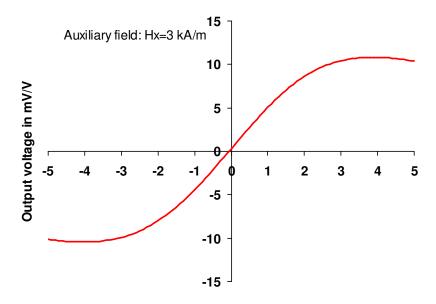


Figure 3: Pad annotation and definition of field direction for KMY & KMZ



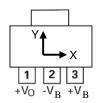
Field Strength Hy in kA/m

Figure 4: Characteristic output curve of KMY & KMZ for an auxiliary field strength of Hx=3 kA/m



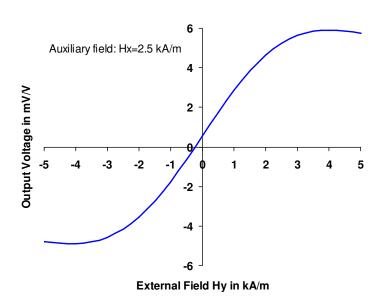
KMY 21

In contrast to the KMY20 sensor products, the **KMY 21 M** consists of a half bridge, making the sensor well suited for dynamic measurements.

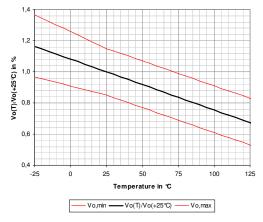


It contains an internal magnet, which provides an auxiliary filed of approx. 2.5 kA/m.

Figure 5: Characteristic curve for KMY21M



TEMPERATURE DEPENDENCIES





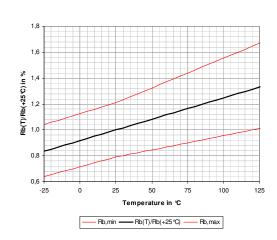
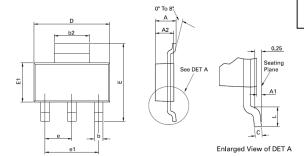


Figure 7: bridge resistance related to room temperature value



PACKAGES

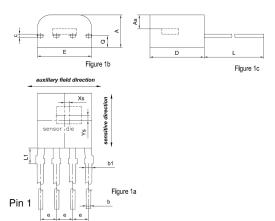
SOT223



Recommended solder reflow process for all packages according to IPC/JEDEC J-STD-020D (Pb-Free Process)

DIM Millimeters		Inches		DIM	Millimeters		Inches		
	Min	Max	Min	Max		Min	Max	Min	Max
Α	-	1.80	-	0.071	e	2.30 BSC		0.0905 BSC	
A1	0.02	0.10	0.0008	0.004	e1	4.60	BSC	0.181	BSC
b	0.66	0.84	0.026	0.033	E	6.70	7.30	0.264	0.287
b2	2.90	3.10	0.114	0.122	E1	3.30	3.70	0.130	0.146
С	0.23	0.33	0.009	0.013	L	0.90	-	0.355	-
D	6.30	6.70	0.248	0.264	-	-	-	-	-

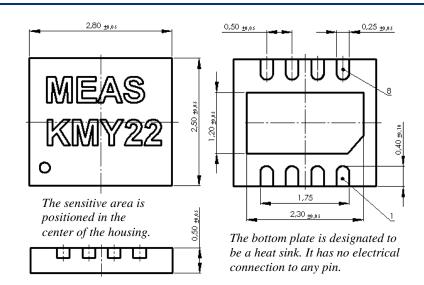
E-LINE 4 PIN



	Milimeter			Inches			
DIE POS.	KMZ20S	KMZ20M	tolerances	KMZ20S	KMZ20M	tolerances	
Xs	+0.05	+0.05	+/-0.10	+0.002	+0.002	+/-0.004	
Ys	+0.50	+0.50	+/-0.10	+0.02	+0.02	+/- 0.004	
As	1.05	1.05	+/-0.10	0.041	0.041	+/-0.004	
	Millmeter				Inches		
DIM	min.	typ.	max.	min.	typ.	max.	

		Millmeter		Inches		
DIM	min.	typ.	max.	min.	typ.	max.
Α	2.4		2.8	0.094		0.110
b	0.35		0.48	0.0138		0.0189
b1	0.45		0.60	0.0178		0.024
С	0.25		0.35	0.0098		0.0138
D	4.0		4.4	0.157		0.173
E	3.8		4.4	0.150		0.173
L	12.0		14.0	0.472		0.551
е	NOM. 1.25			NOM. 0.049		
L1	1.1		1.3	0.043		0.051

UTDFN8 2.5X2.8 MM



DIE LAYOUT AND DIMENSIONS ON REQUEST



ORDERING CODE

DEVICE	DIE	PACKAGE	INTERNAL MAGNET	PART NUMBER
MR174B	full bridge	wafer	n/a	on request
MRHB	half bridge	wafer	n/a	on request
KMY 20 S	full bridge	SOT-223	NO	G-MRCO-006
KMY 20 M	full bridge	SOT-223	YES	G-MRCO-001
KMY 21 M	half bridge	SOT-223	YES	G-MRCO-011
KMZ 20 S	full bridge	E-Line	NO	G-MRCO-007
KMZ 20 M	full bridge	E-Line	YES	G-MRCO-003
KMY 22	full bridge	UTDFN8	NO	on request

ORDERING INFORMATION

Measurement Specialties, Inc. 1000 Lucas Way Hampton, VA 23666 Tel: 1-800-555-1551 Fax: 1-757-766-4297

Email: sales@meas-spec.com Web: www.meas-spec.com Europe MEAS Deutschland GmbH Hauert 13, D-44227 Dortmund, Germany.

Phone: +49-(0)231-9740-0 Fax: +49-(0)231-9740-20 Email: info.de@measspec.com

Web: www.meas-spec.com

Measurement Specialties China Ltd.

No. 26, Langshan Road, Shenzhen High-tech Park (North) Nanshan District, Shenzhen, China 518107 Phone: +86-755-33305088 Fax: +86-755-33305099

Email: info.cn@meas-spec.com Web: www.meas-spec.com

The information in this sheet has been carefully reviewed and is believed to be accurate; however, no responsibility is assumed for inaccuracies. Furthermore, this information does not convey to the purchaser of such devices any license under the patent rights to the manufacturer. Measurement Specialties, Inc. reserves the right to make changes without further notice to any product herein. Measurement Specialties, Inc. makes no warranty, representation or guarantee regarding the suitability of its product for any particular purpose, nor does Measurement Specialties, Inc. assume any liability arising out of the application or use of any product or circuit and specifically disclaims any and all liability, including without limitation consequential or incidental damages. Typical parameters can and do vary in different applications. All operating parameters must be validated for each customer application by customer's technical experts. Measurement Specialties, Inc. does not convey any license under its patent rights nor the rights of others